

STANDARD RECOVERY DIODES
Hockey Puk Version
Features

- Wide current range
- High voltage ratings up to 3200V
- High surge current capabilities
- Diffused junction
- Hockey Puk version
- Case style B-43

1400A
Typical Applications

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications



case style B-43

Major Ratings and Characteristics

Parameters	SD1100C..C		Units
	04 to 20	25 to 32	
$I_{F(AV)}$	1400	1100	A
@ T_{hs}	55	55	°C
$I_{F(RMS)}$	2500	2000	A
@ T_{hs}	25	25	°C
I_{FSM} @ 50Hz	13000	10500	A
@ 60Hz	13600	11000	A
I^2t @ 50Hz	846	551	KA ² s
@ 60Hz	772	503	KA ² s
V_{RRM} range	400 to 2000	2500 to 3200	V
T_J	- 40 to 180	- 40 to 150	°C

ELECTRICAL SPECIFICATIONS**Voltage Ratings**

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = T_J$ max. mA
SD1100C..C	04	400	500	15
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
	25	2500	2600	
	30	3000	3100	
	32	3200	3300	

Forward Conduction

Parameter		SD1100C..C		Units	Conditions			
		04 to 20	25 to 32					
I _{F(AV)}	Max. average forward current @ Heatsink temperature	1400(795)	1100(550)	A	180° conduction, half sine wave			
		55(85)	55(85)	°C	Double side (single side) cooled			
I _{F(RMS)}	Max. RMS forward current	2500	2000	A	@ 25°C heatsink temperature double side cooled			
I _{FSM}	Max. peak, one-cycle forward, non-repetitive surge current	13000	10500	A	t = 10ms	No voltage	Sinusoidal halfwave, Initial T _J = T _J max.	
		13600	11000		t = 8.3ms	reapplied		
		10930	8830		t = 10ms	100% V _{RRM}		
		11450	9250		t = 8.3ms	reapplied		
I ² t	Maximum I ² t for fusing	846	551	KA ² s	t = 10ms	No voltage		
		772	503		t = 8.3ms	reapplied		
		598	390		t = 10ms	100% V _{RRM}		
		546	356		t = 8.3ms	reapplied		
I ² √t	Maximum I ² √t for fusing	8460	5510	KA ² √s	t = 0.1 to 10ms, no voltage reapplied			
V _{F(TO)1}	Low level value of threshold voltage	0.78	0.84	V	(16.7% x π x I _{F(AV)}) < I < π x I _{F(AV)} , T _J = T _J max.			
V _{F(TO)2}	High level value of threshold voltage	0.94	0.88		(I > π x I _{F(AV)}), T _J = T _J max.			
r _{f1}	Low level value of forward slope resistance	0.35	0.40	mΩ	(16.7% x π x I _{F(AV)}) < I < π x I _{F(AV)} , T _J = T _J max.			
r _{f2}	High level value of forward slope resistance	0.26	0.38		(I > π x I _{F(AV)}), T _J = T _J max.			
V _{FM}	Max. forward voltage drop	1.31	1.44	V	I _{pk} = 1500A, T _J = T _J max, t _p = 10ms sinusoidal wave			

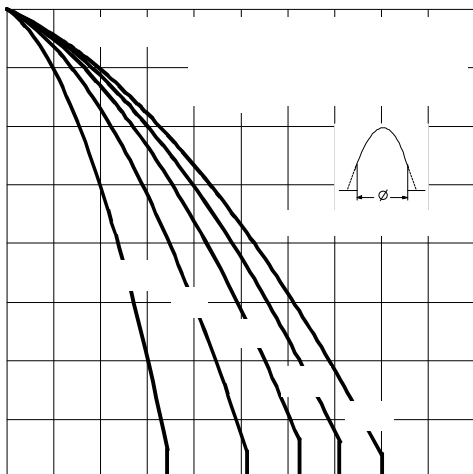


Fig. 3 - Current Ratings Characteristics

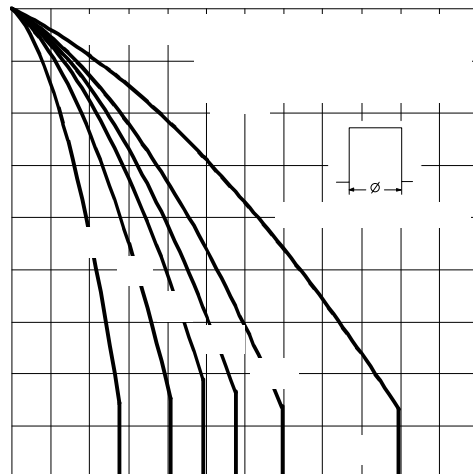


Fig. 4 - Current Ratings Characteristics

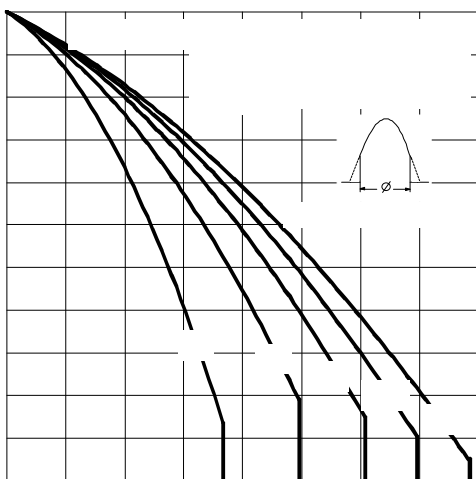


Fig. 5 - Current Ratings Characteristics

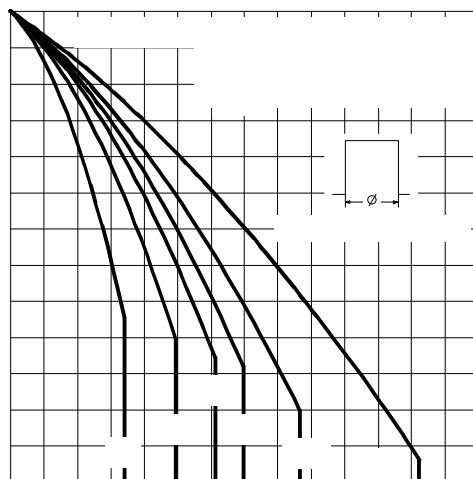


Fig. 6 - Current Ratings Characteristics

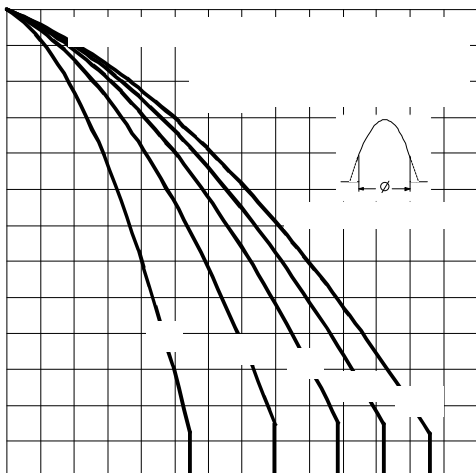


Fig. 7 - Current Ratings Characteristics

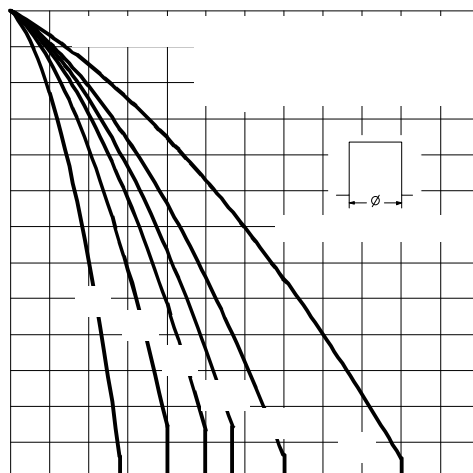


Fig. 8 - Current Ratings Characteristics

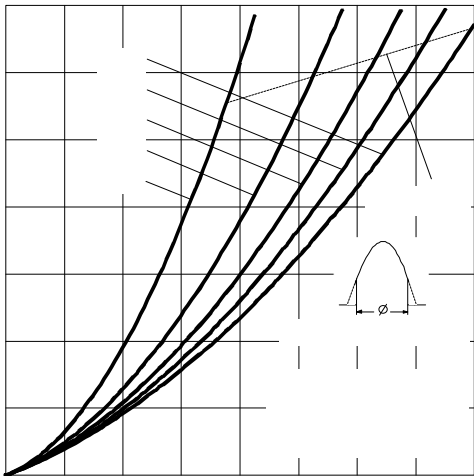


Fig. 9 - Forward Power Loss Characteristics

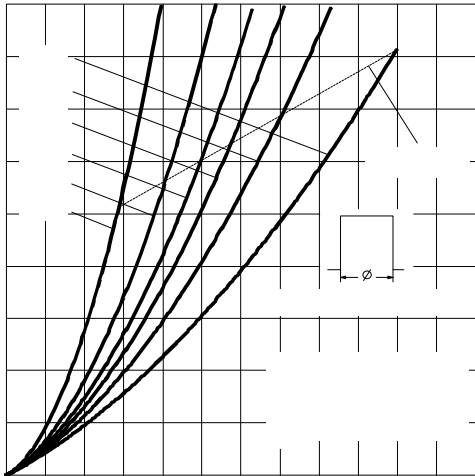


Fig. 10 - Forward Power Loss Characteristics

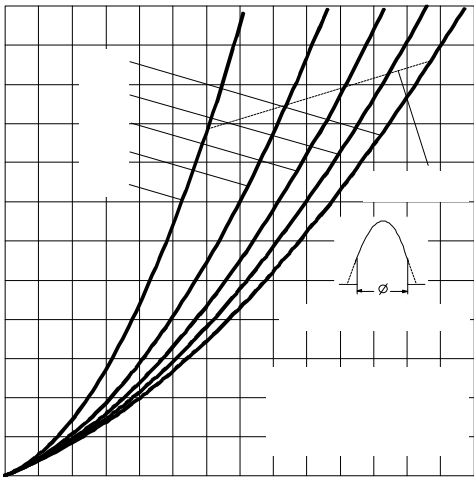


Fig. 11 - Forward Power Loss Characteristics

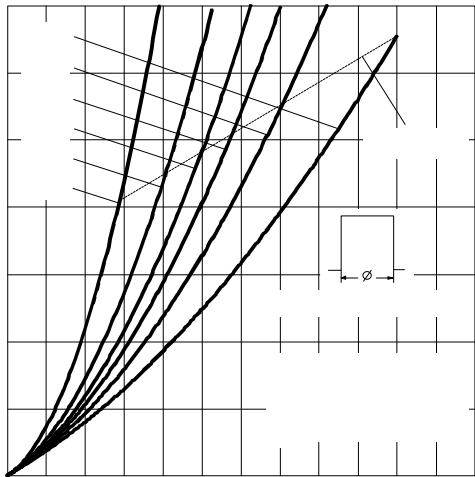


Fig. 12 - Forward Power Loss Characteristics

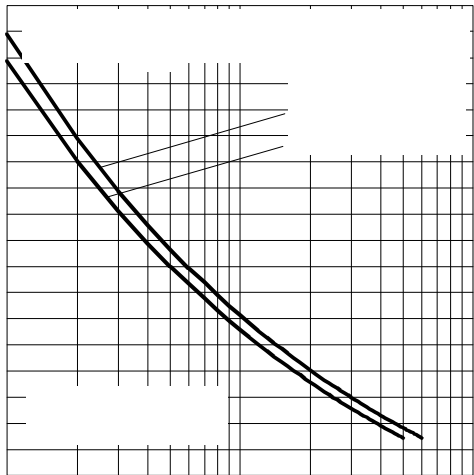


Fig. 13 - Maximum Non-Repetitive Surge Current

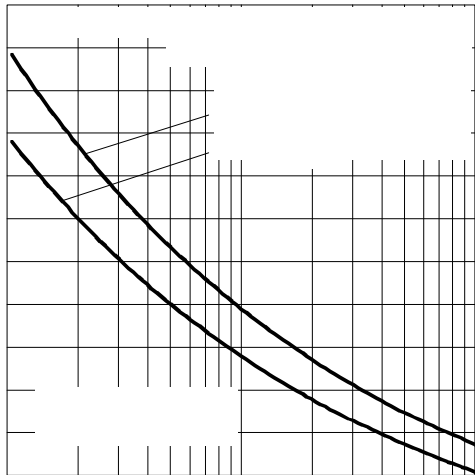


Fig. 14 - Maximum Non-Repetitive Surge Current

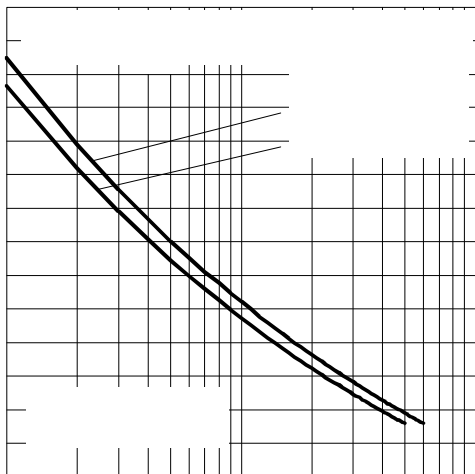


Fig. 15 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

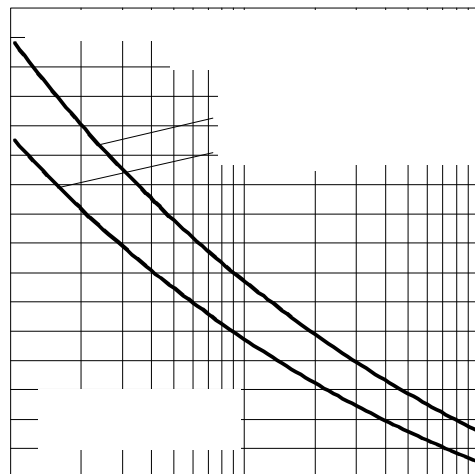


Fig. 16 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

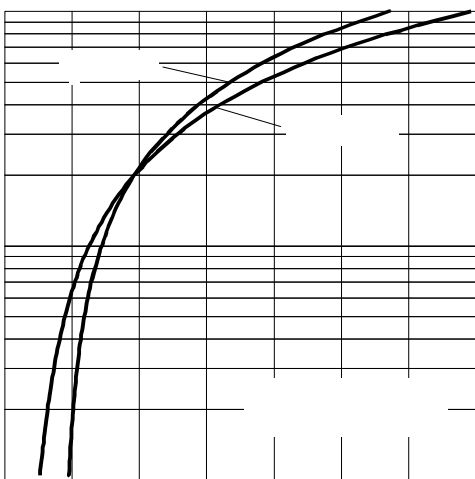


Fig. 17 - Forward Voltage Drop Characteristics



Fig. 18 - Forward Voltage Drop Characteristics

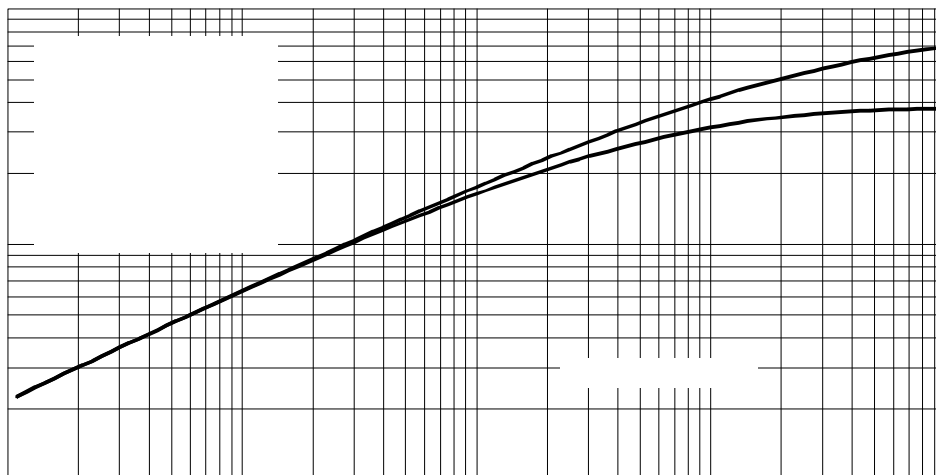


Fig. 19 - Thermal Impedance Z_{thJC} Characteristics

Thermal and Mechanical Specifications

Parameter	SD1100C..C		Units	Conditions
	04 to 20	25 to 32		
T_J Max. junction operating temperature range	-40 to 180	-40 to 150	°C	
T_{stg} Max. storage temperature range	-55 to 200	-55 to 200		
R_{thJ-hs} Max. thermal resistance, junction to heatsink	0.076 0.038		K/W	DC operation single side cooled DC operation double side cooled
F Mounting force, $\pm 10\%$	9800 (1000)		N (Kg)	
wt Approximate weight	83		g	
Case style	B - 43			See Outline Table

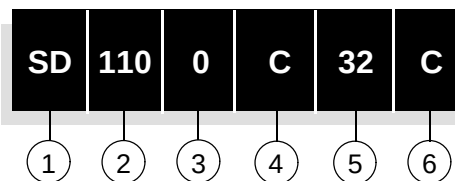
 ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.007	0.007	0.005	0.005	K/W	$T_J = T_J \text{ max.}$
120°	0.008	0.008	0.008	0.008		
90°	0.010	0.010	0.011	0.011		
60°	0.015	0.015	0.016	0.016		
30°	0.026	0.026	0.026	0.026		

Ordering Information Table

Device Code



- 1** - Diode
- 2** - Essential part number
- 3** - 0 = Standard recovery
- 4** - C = Ceramic Puk
- 5** - Voltage code: Code x 100 = V_{RRM} (See Voltage Ratings table)
- 6** - C = Puk Case B - 43

Outline Table

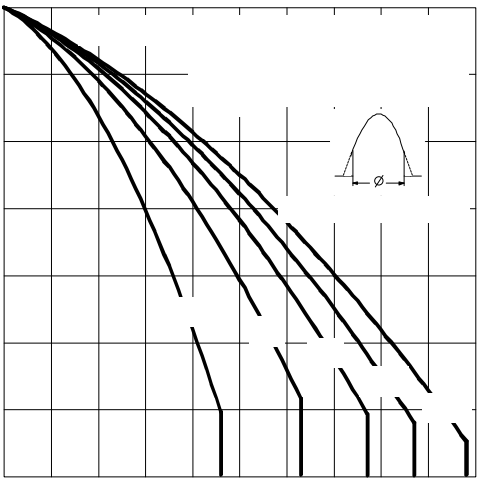
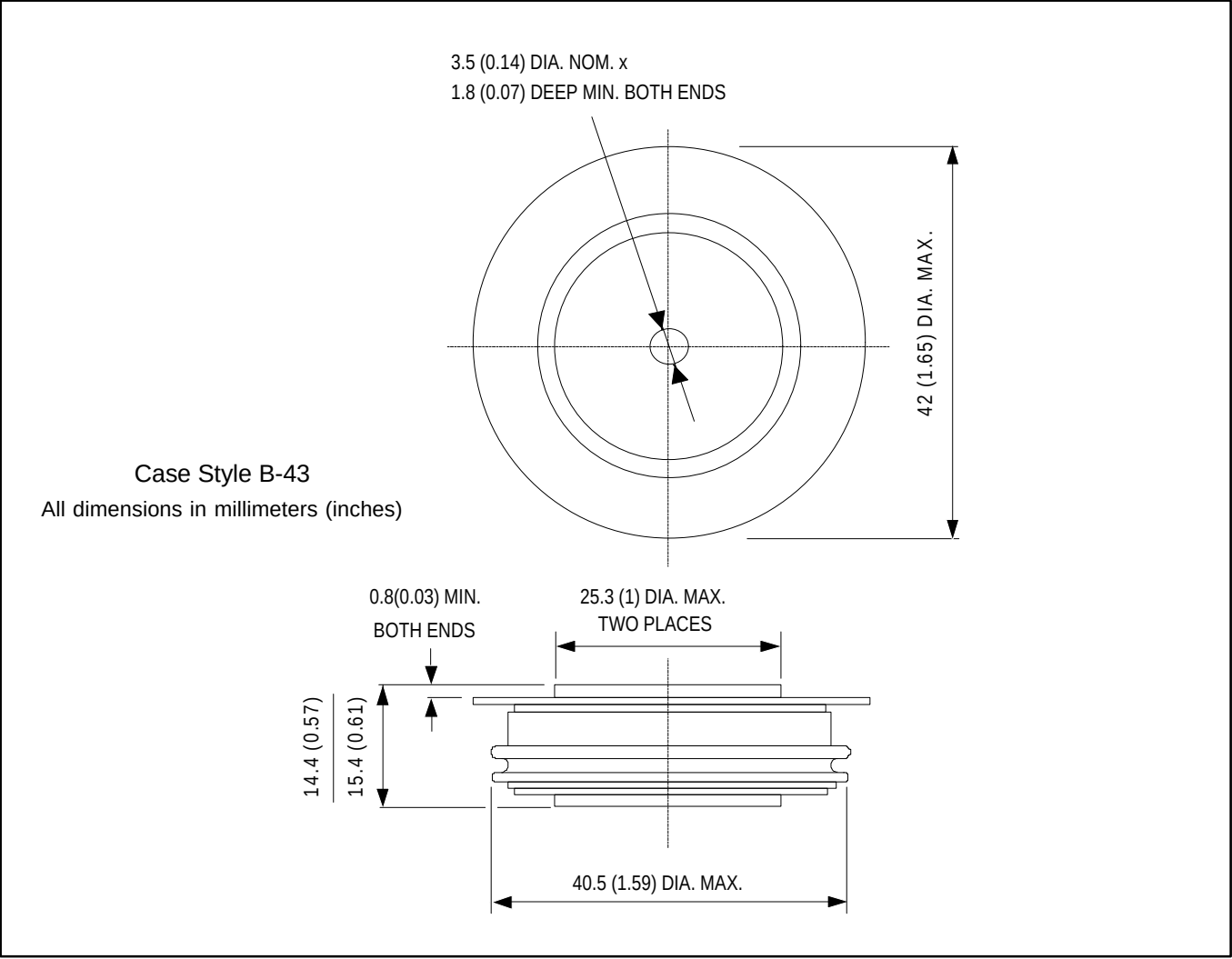


Fig. 1 - Current Ratings Characteristics

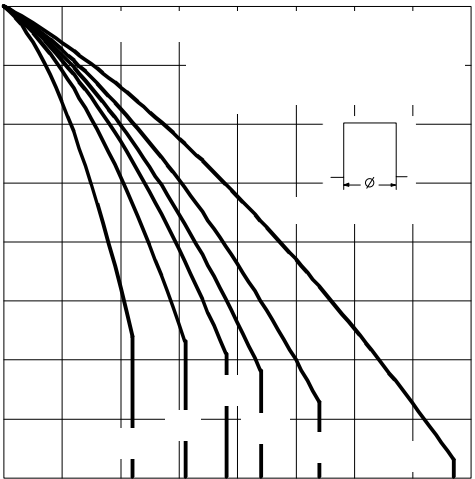


Fig. 2 - Current Ratings Characteristics